

NP90N04MUK, NP90N04NUK MOS FIELD EFFECT TRANSISTOR

R07DS0601EJ0200 Rev.2.00 May 24, 2018

Description

These products are N-channel MOS Field Effect Transistors designed for high current switching applications.

Features

- Super low on-state resistance $R_{DS(on)} = 2.8 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, I_D = 45 \text{ A})$
- Low C_{iss} : $C_{iss} = 4700 \text{ pF TYP}$. $(V_{DS} = 25 \text{ V})$
- Designed for automotive application and AEC-Q101 qualified

Ordering Information

Part No.	Lead Plating	Packing	Package
NP90N04MUK-S18-AY *1	Pure Sn (Tin)	Tube 50 p/tube	TO-220 (MP-25K)
NP90N04NUK-S18-AY *1			TO-262 (MP-25SK)

Note: *1 Pb-free (This product does not contain Pb in the external electrode)

Absolute Maximum Ratings (T_A = 25°C)

Item	Symbol	Ratings	Unit
Drain to Source Voltage (V _{GS} = 0 V)	VDSS	40	V
Gate to Source Voltage (V _{DS} = 0 V)	V _{GSS}	±20	V
Drain Current (DC) ($T_c = 25^{\circ}C$)	I _{D(DC)}	±90	A
Drain Current (pulse) *1, 3	I _{D(pulse)}	±360	A
Total Power Dissipation ($T_c = 25^{\circ}C$)	P _{T1}	176	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.8	W
Channel Temperature	T _{ch}	175	°C
Storage Temperature	T _{stg}	-55 to 175	°C
Repetitive Avalanche Current *2, 3	I _{AR}	43	A
Repetitive Avalanche Energy *2, 3	Ear	185	mJ

Thermal Resistance

Channel to Case Thermal Resistance	Rth(ch-C) *3	0.85	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A) *3	83.3	°C/W

Notes: *1 T_C = 25°C, P_W \leq 10 μ s, Duty Cycle \leq 1%

*2 R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

*3 Not subject of production test. Verified by design/characterization.



Electrical Characteristics (T_A = 25°C)

Item	Symbol	MIN.	TYP.	MAX.	Unit	Test Conditions	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	V _{DS} = 40 V, V _{GS} = 0 V	
Gate Leakage Current	I _{GSS}			±100	nA	V_{GS} = ±20 V, V_{DS} = 0 V	
Gate to Source Threshold Voltage	V _{GS(th)}	2.0	3.0	4.0	V	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	
Forward Transfer Admittance *1	y _{fs}	35	70	_	S	V _{DS} = 5 V, I _D = 45 A	
Drain to Source On-state Resistance *1	R _{DS(on)}	—	2.35	2.80	mΩ	V _{GS} = 10 V, I _D = 45 A	
Input Capacitance *2	Ciss	—	4700	7050	pF	V _{DS} = 25 V	
Output Capacitance *2	Coss	_	660	990	pF	$V_{GS} = 0 V$	
Reverse Transfer Capacitance *2	Crss	_	270	490	pF	f = 1 MHz	
Turn-on Delay Time *2	t _{d(on)}	_	28	70	ns	V _{DD} = 20 V, I _D = 45 A	
Rise Time *2	tr	_	14	40	ns	V _{GS} = 10 V	
Turn-off Delay Time *2	t _{d(off)}	_	70	140	ns	R _G = 0 Ω	
Fall Time *2	t _f	_	10	30	ns		
Total Gate Charge *2	Q _G	_	80	120	nC	V _{DD} = 32 V	
Gate to Source Charge	Q _{GS}		21		nC	V _{GS} = 10 V	
Gate to Drain Charge	Q _{GD}	—	20	—	nC	I _D = 90 A	
Body Diode Forward Voltage *1	V _{F(S-D)}	_	0.9	1.5	V	I _F = 90 A, V _{GS} = 0 V	
Reverse Recovery Time	t _{rr}	—	52	—	ns	I _F = 90 A, V _{GS} = 0 V	
Reverse Recovery Charge	Qrr		78		nC	di/dt = 100 A/µs	

 V_{GS}

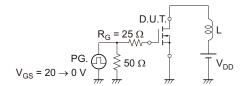
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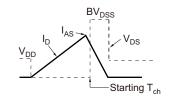
0

Note: *1 Pulsed test

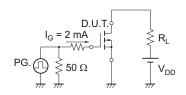
Note; *2 Not subject of production test. Verified by design/characterization.

TEST CIRCUIT 1 AVALANCHE CAPABILITY

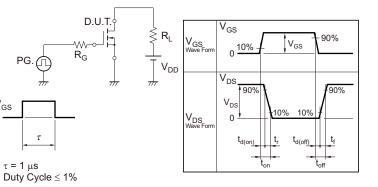




TEST CIRCUIT 3 GATE CHARGE



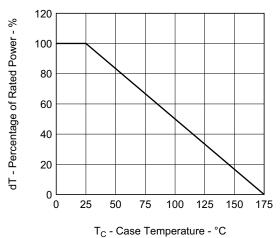
TEST CIRCUIT 2 SWITCHING TIME

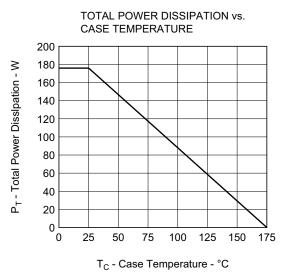




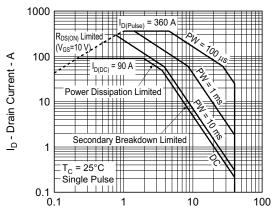
Typical Characteristics (T_A = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



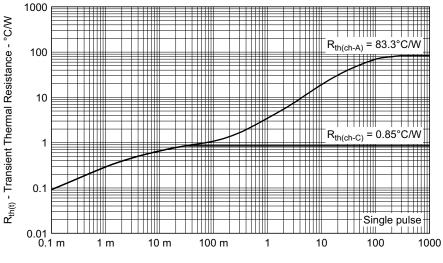


FORWARD BIAS SAFE OPERATING AREA



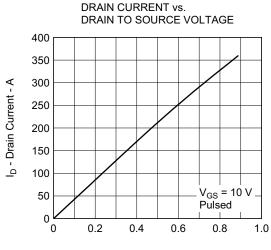


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

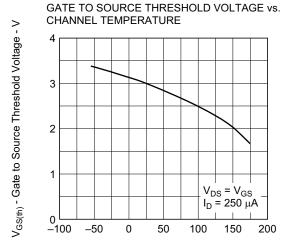


PW - Pulse Width - s

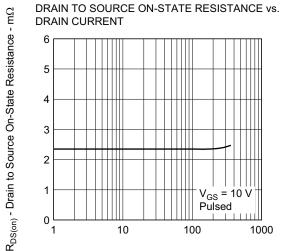




V_{DS} - Drain to Source Voltage - V



T_{ch} - Channel Temperature - °C



4 3 2 1 V_{GS} = 10 V Pulsed 0

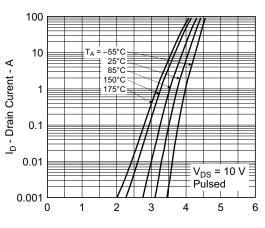
I_D - Drain Current - A

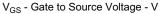
100

1000

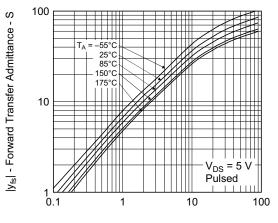
10

FORWARD TRANSFER CHARACTERISTICS

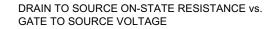


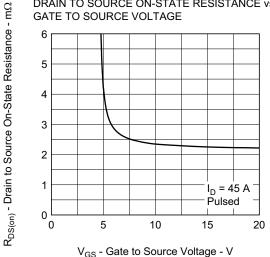


FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



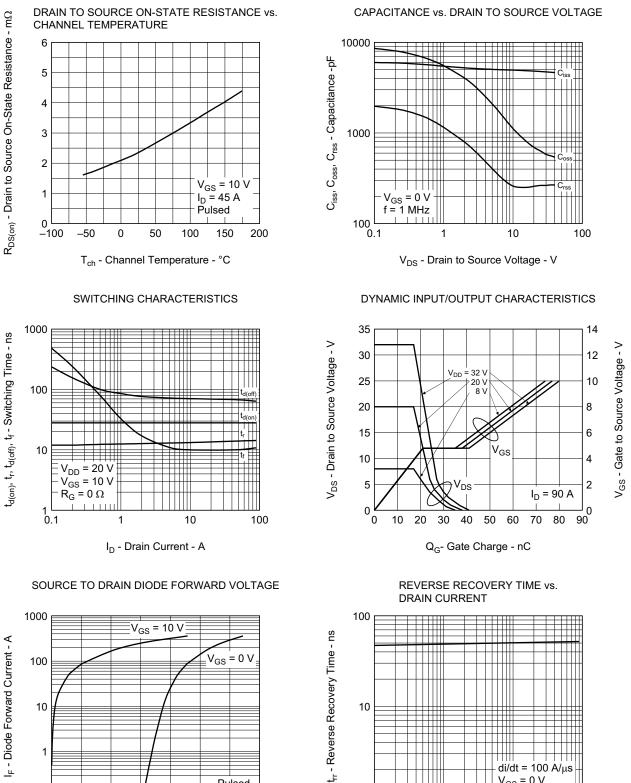
I_D - Drain Current - A

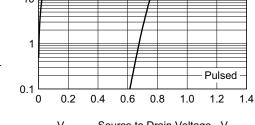




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V_{F(S-D)} - Source to Drain Voltage - V



1 └ 0.1

111

IF - Drain Current - A

10

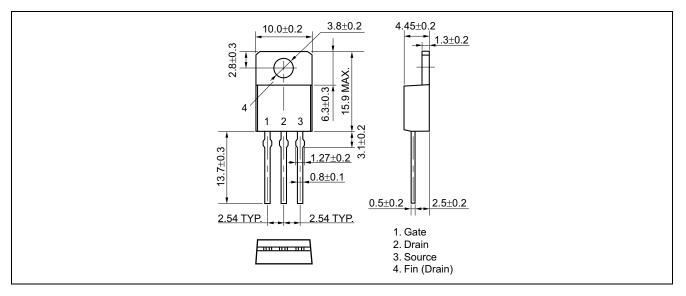
1

di/dt = 100 A/µs V_{GS} = 0 V

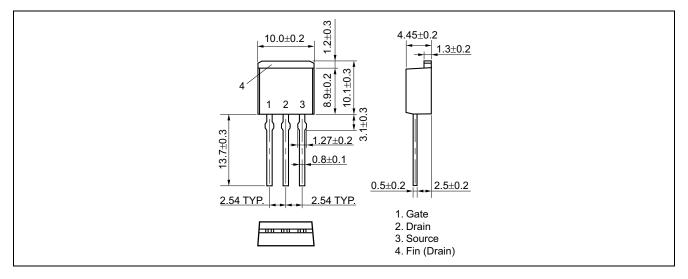
100

Package Drawing (Unit: mm)

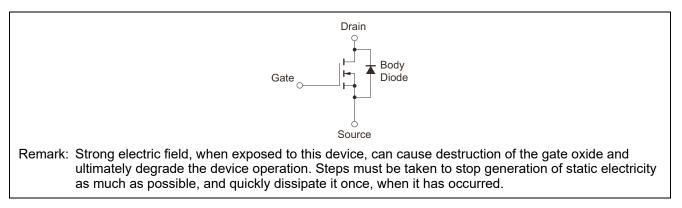
TO-220 (MP-25K) (Mass: 1.9 g TYP.)



TO-262 (MP-25SK) (Mass: 1.8 g TYP.)



Equivalent Circuit



Revision History

NP90N04MUK, NP90N04NUK Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Jan 11, 2012	—	First Edition Issued	
2.00	May 24 ,2018	1	Note 3 was added	
		2	Note 2 was added	

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